TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

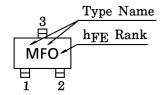
2 S C 5 1 0 6

FOR VCO APPLICATION

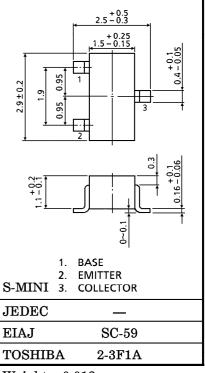
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	v_{CEO}	10	V
Emitter-Base Voltage	v_{EBO}	3	V
Base Current	$I_{\mathbf{B}}$	15	mA
Collector Current	$I_{\mathbf{C}}$	30	mA
Collector Power Dissipation	PC	150	mW
Junction Temperature	Tj	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$T_{ m stg}$	-55~125	°C

MARKING



Unit in mm



Weight: 0.012g

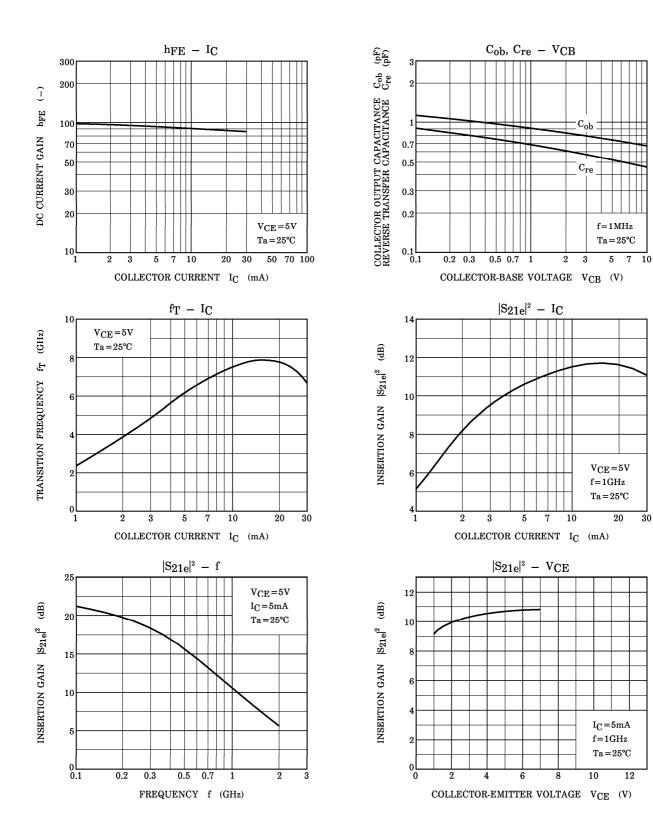
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 10V, I_{E} = 0$	_	_	0.1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_{C}=0$	_	_	0.1	μ A
DC Current Gain	h _{FE} (Note 1)	$V_{CE}=5V, I_{C}=5mA$	80	_	240	_
Transition Frequency	${ m f_T}$	$V_{CE}=5V, I_{C}=5mA$	4	6	_	GHz
Insertion Gain	$ \mathrm{S}_{21\mathrm{e}} ^2$	$V_{CE}=5V$, $I_{C}=5mA$, $f=1GHz$	7	11	_	dB
Output Capacitance	$C_{\mathbf{ob}}$	$V_{CB}=5V$, $I_E=0$, $f=1MHz$	_	0.7	_	рF
Reverse Transfer Capacitance	$\mathrm{c_{re}}$	(Note 2)	_	0.5	0.9	pF
Collector-Base Time Constant	C _c .rbb'	V_{CB} =15V, I_{C} =3mA, f=30MHz	_	5.5	10	ps

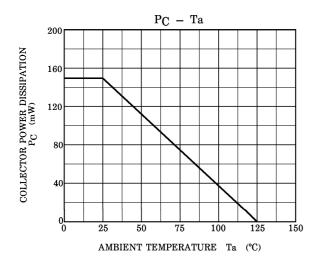
(Note 1) h_{FE} Classification $O:80{\sim}160$, $Y:120{\sim}240$

(Note 2) C_{re} is measured by 3 terminal method with capacitance bridge.

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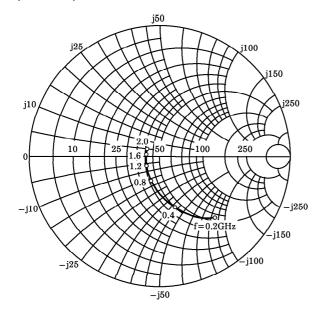
S-Parameter $Z_O = 50\Omega$, $Ta = 25^{\circ}C$ $V_{CE} = 5V$, $I_C = 5mA$

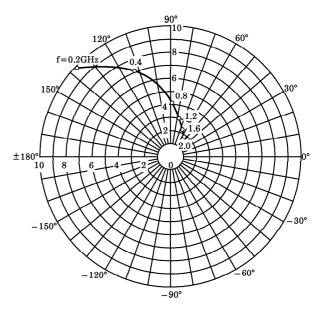
frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.654	-45.3	9.794	136.6	0.047	64.8	0.775	-27.8
400	0.414	-75.6	7.062	112.6	0.071	58.7	0.570	-35.0
600	0.273	- 94.9	5.232	98.7	0.090	58.5	0.472	-35.8
800	0.193	-111.7	4.118	89.4	0.108	59.5	0.424	-35.5
1000	0.146	-128.1	3.412	82.0	0.127	60.4	0.398	-35.5
1200	0.116	-147.4	2.927	75.5	0.147	61.0	0.381	-36.2
1400	0.101	-169.6	2.571	69.8	0.169	60.7	0.373	-37.9
1600	0.098	171.6	2.299	64.4	0.189	59.5	0.363	-40.4
1800	0.105	155.8	2.079	59.8	0.208	58.6	0.351	-43.5
2000	0.118	142.1	1.928	55.4	0.230	58.4	0.338	-46.1

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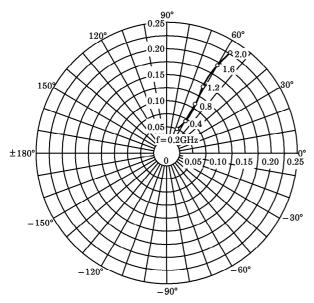
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$

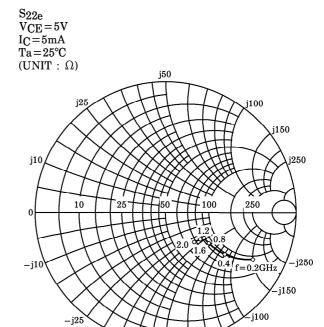












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